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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/945,432	09/04/2001	Chung Liu	TS00-523	2709
7	590 10/15/2002			
GEORGE O. SAILE 20 MCINTOSH DRIVE POUGHKEEPSIE, NY 12603			EXAMINER	
			NGUYEN, HA T	
			ART UNIT	PAPER NUMBER
			2812	
		DATE MAILED: 10/15/2002		

Please find below and/or attached an Office communication concerning this application or proceeding.

				In		
		Application No.	pplicant(s)			
' Office Action Summary		09/945,432	LIU ET AL.			
		Examiner	Art Unit			
		Ha T. Nguyen	2812			
Period fo	The MAILING DATE of this communications	n appears on the cover sheet	with the correspondence ad	dress		
A SHOTHE I - Exter after - If the - If NO - Failu - Any r	ORTENED STATUTORY PERIOD FOR R MAILING DATE OF THIS COMMUNICATI usions of time may be available under the provisions of 37 C SIX (6) MONTHS from the mailing date of this communicati uperiod for reply specified above is less than thirty (30) days uperiod for reply is specified above, the maximum statutory uperiod for reply within the set or extended period for reply will, by uperly received by the Office later than three months after the upper of the provided of the control of the c	ON. FR 1.136(a). In no event, however, mayon. i, a reply within the statutory minimum of period will apply and will expire SIX (6) Notes that the statute, cause the application to become	y a reply be timely filed thirty (30) days will be considered timel MONTHS from the mailing date of this of BABANDONED (35 U.S.C. § 133).	y. ommunication.		
1)⊠	Responsive to communication(s) filed or	n <u>22 July 2002</u> .				
2a)⊠	This action is FINAL . 2b)	This action is non-final.				
3) <u>□</u> Dispositi	Since this application is in condition for a closed in accordance with the practice u ion of Claims	allowance except for formal r inder <i>Ex parte Quayle</i> , 1935	matters, prosecution as to the C.D. 11, 453 O.G. 213.	ne merits is		
4)⊠	Claim(s) <u>1-3,6-13,17-23 and 26-31</u> is/are	e pending in the application.				
	4a) Of the above claim(s) is/are with	thdrawn from consideration.	•	-		
5)	Claim(s) is/are allowed.					
6)⊠	Claim(s) 1-3,6-13,17-23 and 26-31 is/are	rejected.				
7)	Claim(s) is/are objected to.					
8)□	Claim(s) are subject to restriction	and/or election requirement.				
Applicat	ion Papers					
	The specification is objected to by the Exa					
10)	The drawing(s) filed on is/are: a)□					
	Applicant may not request that any objection					
11)	The proposed drawing correction filed on		_ disapproved by the Examir	ner.		
	If approved, corrected drawings are required					
•	The oath or declaration is objected to by t	ne Examiner.				
•	under 35 U.S.C. §§ 119 and 120					
	Acknowledgment is made of a claim for f	foreign priority under 35 U.S.	C. § 119(a)-(d) or (f).			
a)	☐ All b)☐ Some * c)☐ None of:					
	1. Certified copies of the priority docu					
	2. Certified copies of the priority docu					
* (Copies of the certified copies of th application from the Internation See the attached detailed Office action for 	nal Bureau (PCT Rule 17.2(a	a)).	l Stage		
14) 🔲 .	Acknowledgment is made of a claim for do	omestic priority under 35 U.S	S.C. § 119(e) (to a provisiona	al application).		
	a) The translation of the foreign langua Acknowledgment is made of a claim for de					
Attachme	nt(s)					
2) 🔲 Noti	ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (PTO-9 rmation Disclosure Statement(s) (PTO-1449) Paper	948) 5) Notice	riew Summary (PTO-413) Paper N e of Informal Patent Application (P :			

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DETAILED ACTION

Notice to applicant

1. Applicant's Amendment and Response to the Office Action mailed 3-18-02 has been entered and made of record (Paper No. 4).

Response to Amendment

2. In view of Applicant's cancellation of the claims, the objection for informalities to and rejection of claims 4, 5, 14, 15, 24, and 25 under 35 U.S.C. 112 first paragraph have been rendered moot.

In view of Applicant's amendment to the claims, the objection to claims 11-13, 16-23, and 26-31, for informalities, has been withdrawn.

Applicant's arguments with regard to the rejections under 35 U.S.C. 103 have been fully considered, but they are not deemed to be persuasive for at least the following reasons.

Applicant's argued that Kida discloses the use of large via holes to restric insulator layer cracking but does not specify other requirements concerning the shapes of the via openings to restrict cracking and does not address the problem of void formation. The examiner disagrees, Kida et al. (U.S. Patent 6313540, hereinafter Kida) discloses the need for a distribution of stress through vias to prevent breakage and /or crack of the insulating film underlying the pad from occurring (see par. bridging cols. 4 and 5). Figs. 7a- 7h discloses different pattern suitable to perform this function. The via holes (trenches) in Fig. 7a are provided in rows and columns with constant interval, therefore Fig. 7a meet the limitations concerning the horizontal and vertical trenches wherein none of the horizontal trenches intersects any of the vertical trenches (or non-intersecting layout). Applicants' arguments concerning Kida not addressing the void formation problem are irrelevant since this is not a limitation of the claims.

Therefore Kida alone or combined with the references used do make obvious the claimed invention.

Applicants are referred to the modified rejection given below.

Claim Rejections - 35 USC § 103

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3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103® and potential 35 U.S.C. 102(f) or (g) prior art under 35 U.S.C. 103(a).

4. Claims 1, 2, 6-12, and 16-19 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kida et al., U.S. Patent 6313540 (Hereinaster Kida).

[Claims 1 and 11] Referring to Figs. 5, 6a-6j, 7a, 9, Kida discloses a method of forming a bonding pad that is immune to IMD cracking, comprising: providing a partially processed semiconductor wafer 11 having all metal levels completed (see Figs. 5 and 9); forming a blanket dielectric layer 15 over the uppermost metal level; patterning and etching said dielectric layer to form horizontal and vertical arrays of trenches 21 passing through said dielectric layer and separating said dielectric layer into cells (see Figs 6d, 7a); filling said trenches with a conducting material 23; planarizing the conducting material (see Fig. 6f); depositing bonding metal patterns 24; bonding wires 18 onto said bonding metal patterns; forming a passivation layer 17. But it does not disclose expressly performing CMP to planarize and that the horizontal and vertical arrays of trenches passing through said dielectric layer according to a nonintersecting layout. However, Kida also disclose that the shape of the openings 21 does not have to be square, but can have other shape (see col. 5, lines 13-42), when the openings in Fig. 7a have more elongated shape, the non-intersecting is clearly shown. Besides, the examiner takes Official Notice that CMP is a well known method of planarization used to obtain global planarization.

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[Claims 2 and 12] Kida also discloses wherein said dielectric layer is composed of materials from the set: silicon oxide, silicon nitride, silicon oxynitride (See col. 4, lines 1-5);

[Claims 6-8 and 16-18] wherein the filling of said trenches with a conducting material is accomplished using a plug process; wherein the filling of said trenches with a conducting material is accomplished using a W plug process; wherein the filling of said trenches with a conducting material is accomplished using a plug process from the set: Al plug, Cu plug, silicide plug (See col. 4, lines 6-14);

[Claims 9 and 19] wherein the width of said trenches is 0.6 micrometers (See col. 6, lines 7-11), the contact area of the pad and the via hole gives the dimension of the width of the via hole because the whole cross section of the via hole contact the pad (see Fig. 5). But it does not disclose the exact range for the width of the trenches. However any variation in width in the present claims is obvious in light of the cited art, because the changes in width produce no unexpected function. The routine varying of parameters to produce expected changes are within the ability of one of ordinary skill in the art. Patentability over the prior art will only occur if the parameter variation produces an unexpected result. In re Aller, Lacey and Hall, 105 U.S.P.Q. 233, 235. In re Reese 129 U.S.P.Q. 402, 406.

[Claim 10] Kida also discloses wherein the separation between neighboring horizontal trenches and neighboring vertical trenches is between 0.2 and 20 micrometers (See Fig. 5 and col. 6, lines 7-11) the Fig. shows that the separation between neighboring trenches is less than twice the width of the via hole, therefore, it is between 0.6 and 1.2 micrometers, a range within the claimed 0.2 and 20 micrometers range.

Therefore, it would have been obvious to use Kida teaching to obtain the invention as specified in claims 1, 2, 6-12, and 16-19.

5. Claims 1, 2, 6-9, 11, 12, 16-19, 20-22, and 26-31 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kida, as applied to claims 1, 2 and 6-10 above, in view of Huang et al., U.S. Patent 6236114 (Hereinafter Huang).

[Claims 1, 11 and 21] Kida discloses substantially the limitations of claims 1, 11 and 21, as shown above .

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But it does not disclose expressly that the horizontal and vertical arrays of trenches passing through said dielectric layer according to a brick laying layout or a modified brick laying layout. Some may argue that the feature "a nonintersecting layout" of claim 11 is not taught or made obvious by Kida.

However, the missing limitations are well known in the art because Huang discloses these features (See Figs. 1, 2, # 135a,b, 155a,b, 175a,b).

A person of ordinary skill is motivated to modify Kida with Huang to obtain improved adhesion between dielectric and metal layers and to more uniformly release the compressive mechanical stress (see Huang, abstract).

[Claims 2, 6-9, 12, 16-19, 22, and 26-29] The arguments used for the rejection of claims 2 and 6-9 above also apply.

[Claim 20] Kida also discloses wherein the separation between neighboring horizontal trenches and neighboring vertical trenches is between 0.1 and 10 micrometers, as shown in the rejection of claim 10. But it does not disclose expressly that the ratio between the spacing of perpendicular trenches to the spacing of parallel trenches is less then about 1/5, and the spacing of perpendicular trenches is greater than about 0.1 micrometers. However, the missing limitation is well known in the art because Huang discloses this feature (see Fig. 2).

[Claims 30 and 31] The argument for the rejection of claim 10 also applies. Besides Huang also shows that the overlap area in said modified bricklaying layout is between 0.1 and 1 of the overlap area of said bricklaying layout (see Fig. 2).

Therefore, it would have been obvious to combine Kida with Huang to obtain the invention as specified in claims 1, 2, 6-9, 11, 12, 16-19, 21, 22, and 26-31.

6. Claims 3 and 13 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kida, as applied to claims 1, 2, 6-11, 12, and 16-19 above, (or Kida in view of Huang and further) in view of Saran, U.S. Patent 6232662.

Kida (or Kida in view of Huang)discloses substantially the limitations of claims 3 and 13, as shown above.

But it does not disclose expressly that the dielectric layer is a composite of dielectric layers and the methods of forming the dielectric layers.

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However, the missing limitations are well known in the art because Saran discloses these features (See col. 6, line 38- col. 7, line 4). The combined teaching of Kida (or Kida, Huang) and Saran does not disclose the use of HDP oxide. However it would have been obvious for a person of ordinary skill in the art to use HDP to obtain good quality and dense oxide.

A person of ordinary skill is motivated to modify Kida (or Kida, Huang) with Saran to obtain dielectric with low dielectric constant or material with characteristics suitable for a specific application requirements concerning manufacturing cost, product quality and equipments.

Therefore, it would have been obvious to combine Kida (or Kida, Huang) with Saran to obtain the invention as specified in claims 3 and 13.

Conclusion

7. THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for response to this final action is set to expire THREE MONTHS from the date of this action. In the event a first response is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event will the statutory period for response expire later than SIX MONTHS from the date of this final action.

8. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Ha Nguyen whose telephone number is (703)308-2706. The examiner can normally be reached on Monday-Friday from 8:30AM to 6:00PM, except the first Friday of each bi-week.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, John Niebling, can be reached on (703) 308-3325. The fax phone number for this Group is (703) 308-7722.

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Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the Group receptionist whose telephone number is (703) 308-0956.

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Ha Nguyen

Primary Examiner

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